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APPLICATION NO.	FI	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/662,819	(09/16/2003	Hiroji Ebe	031171	031171 1103	
23850	7590	11/30/2004		EXAMINER		
	•	ATZ, QUINTOS, I	FARAHANI, DANA			
1725 K STR SUITE 1000	•			ART UNIT	PAPER NUMBER	
WASHINGT	ON, DC	20006		2814		

DATE MAILED: 11/30/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)					
	10/662,819 EBE ET A						
Office Action Summary	Examiner	Art Unit					
	Dana Farahani	2814	p				
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with	the correspondence add	dress				
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	I36(a). In no event, however, may a reply ly within the statutory minimum of thirty (3 will apply and will expire SIX (6) MONTHS e, cause the application to become ABANI	be timely filed 0) days will be considered timely 5 from the mailing date of this condoned DONED (35 U.S.C. § 133).					
Status							
1)⊠ Responsive to communication(s) filed on <u>14 S</u>	September 2004.	<i>2</i>	•				
2a) ☐ This action is FINAL . 2b) ☑ This	s action is non-final.						
· · · · · · · · · · · · · · · · · · ·	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
 4) Claim(s) 1-19 is/are pending in the application 4a) Of the above claim(s) is/are withdra 5) Claim(s) 1-13 and 17-19 is/are allowed. 6) Claim(s) 14 is/are rejected. 7) Claim(s) 15-16 is/are objected to. 8) Claim(s) are subject to restriction and/or 	wn from consideration.						
Application Papers	,		. سم				
9) The specification is objected to by the Examine	er.						
10) The drawing(s) filed on is/are: a) acc	0) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.						
Applicant may not request that any objection to the	drawing(s) be held in abeyance	. See 37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex	•	=					
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	ts have been received. ts have been received in App prity documents have been re u (PCT Rule 17.2(a)).	lication No ceived in this National S	Stage				
Attachment(s)							
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Sum	nmary (PTO-413) //ail Date					
Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	_	rmal Patent Application (PTO	1-152)				

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) and the Intellectual Property and High Technology Technical Amendments Act of 2002 do not apply when the reference is a U.S. patent resulting directly or indirectly from an international application filed before November 29, 2000. Therefore, the prior art date of the reference is determined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

2. claim 14 is rejected under 35 U.S.C. 102(e) as being anticipated by Petroff et al., hereinafter Petroff (US Patent Application Publication 2002/0162995).

Petroff discloses in figure 1D, a semiconductor substrate 100, and an active layer 104 and 106 formed on the semiconductor substrate and including a quantum structure therein, the quantum structure comprising: a first barrier layer 104 of a first semiconductor crystal having a first lattice constant and a first bandgap; a second barrier layer 106 of a second semiconductor crystal formed on the first barrier layer, the second semiconductor crystal having a second lattice constant and a second bandgap; a plurality of quantum dots 108 formed in the second barrier layer, each of the quantum dots comprising a semiconductor crystal forming a strained system

with respect to the first and second semiconductor crystals and having a lattice constant different from the first lattice constant and a bandgap smaller than any of the first and second bandgaps, each of the quantum dots having a height substantially equal to a thickness of the second barrier layer, the first barrier layer and the second barrier layer being stacked alternately such that the first barrier layer makes a contact with an apex of the quantum dots in the second barrier layer, the first barrier layer and the second barrier layer having respective, different compositions.

Allowable Subject Matter

- 3. Claims 15 and 16 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 4. Claims 1-13 and 17-19 are allowed.
- 5. The following is an examiner's statement of reasons for allowance:

The primary reason for indication of allowability of claims 1-13 is the inclusion therein of the limitation that of the third barrier layer, as defined in claim 1, making a contact with an apex of the quantum dot.

The primary reason for indication of allowability of claims 15 and 16 is the inclusion therein of the limitation that of a mixed crystal InGaAsP layer forming the first and second barrier layer.

The primary reason for indication of allowability of claims 17-19 is the inclusion therein of the limitation that of the quantum dots, as defined in claim 17, are stacked at a predetermined stack number.

Application/Control Number: 10/662,819 Page 4

Art Unit: 2814

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dana Farahani whose telephone number is (571)272-1706. The examiner can normally be reached on M-F 9:00AM - 6:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M Fahmy can be reached on (571)272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

D. Farahani

DOUGLAS WILLE DOUGLAS WILLE DRIMARY EXAMINER